

N-CHANNEL ENHANCEMENT MODE FIELD EFFECT **TRANSISTOR**

Features

Low On-Resistance

Low Gate Threshold Voltage

Low Input Capacitance

Fast Switching Speed

Low Input/Output Leakage

Lead Free/RoHS Compliant (Note 2)

Mechanical Data

Case: SOT-23

Case Material: Molded Plastic. UL Flammability

Classification Rating 94V-0

Moisture Sensitivity: Level 1 per J-STD-020C

Terminal Connections: See Diagram

Terminals: Solderable per MIL-STD-202, Method 208

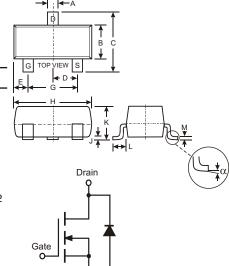
Lead Free Plating (Matte Tin Finish annealed over Alloy 42

leadframe).

Marking (See Page 2): K70

Ordering & Date Code Information: See Page 2

Weight: 0.008 grams (approximate)



SOT-23									
Dim	Min	Max							
Α	0.37	0.51							
В	1.20	1.40							
С	2.30	2.50							
D	0.89	1.03							
E	0.45	0.60							
G	1.78	2.05							
Н	2.80	3.00							
J	0.013	0.10							
K	0.903	1.10							
L	0.45	0.61							
М	0.085	0.180							
	0	8							
All Dimensions in mm									

Maximum Ratings @ T_A = 25 C unless otherwise specified

Characteristic		Symbol	BS870	Units	
Drain-Source Voltage		V_{DSS}	60	V	
Drain-Gate Voltage R _{GS} 1.0M		V_{DGR}	60	V	
Gate-Source Voltage Co	ontinuous	V _{GSS}	20	V	
Drain Current (Note 1)	ontinuous	I _D	250	mA	
Total Power Dissipation (Note 1)		P _d	300	mW	
Thermal Resistance, Junction to Ambient		R _{JA}	417	K/W	
Operating and Storage Temperature Range		T _j , T _{STG}	-55 to +150	С	

Note: 1. Device mounted on FR-5 PCB 1.0 x 0.75 x 0.062 inch pad layout as shown on Diodes, Inc. suggested pad layout AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

2. No purposefully added lead.



Electrical Characteristics @ $T_A = 25$ C unless otherwise specified

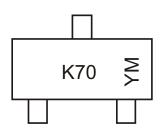
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 3)					•			
Drain-Source Breakdown Voltage	BV _{DSS}	60	80		V	V _{GS} = 0V, I _D = 100 A		
Zero Gate Voltage Drain Current	I _{DSS}			0.5	μA	V _{DS} = 25V, V _{GS} = 0V		
Gate-Body Leakage	I _{GSS}			10	nA	V _{GS} = 15V, V _{DS} = 0V		
ON CHARACTERISTICS (Note 3)								
Gate Threshold Voltage	V _{GS(th)}	1.0	2.0	3.0	V	$V_{DS} = V_{GS}, I_{D} = 250 A$		
Static Drain-Source On-Resistance	R _{DS (ON)}		3.5	5.0		$V_{GS} = 10V, I_D = 0.2A$		
On-State Drain Current	I _{D(ON)}		1.0	0.5	Α	V _{GS} = 10V, V _{DS} = 7.5V		
Forward Transconductance	g _{FS}	80			mS	V _{DS} =10V, I _D = 0.2A		
DYNAMIC CHARACTERISTICS			•	•	•			
Input Capacitance	C _{iss}		22	50	pF			
Output Capacitance	Coss		11	25	pF	$V_{DS} = 10V, V_{GS} = 0V$ f = 1.0MHz		
Reverse Transfer Capacitance	C _{rss}		2.0	5.0	pF	1		
SWITCHING CHARACTERISTICS								
Turn-On Delay Time	t _{D(ON)}		2.0	20	ns	V _{ES} = 10V, R _L = 150 ,		
Turn-Off Delay Time	t _{D(OFF)}		5.0	20	ns	$V_{DS} = 10V, R_D = 100$		

Ordering Information (Note 4)

Device	Packaging	Shipping
BS870-7-F	SOT-23	3000/Tape & Reel

- Notes: 3. Short duration test pulse used to minimize self-heating effect.
 - 4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information

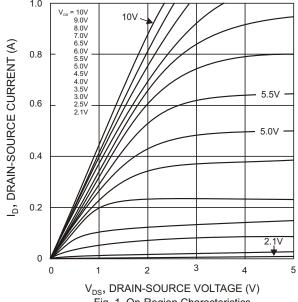


K70 = Product Type Marking Code YM = Date Code Marking Y = Year ex: N = 2002 M = Month ex: 9 = September

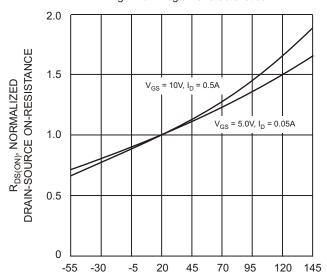
Date Code Key

Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009
Code	J	K	L	М	N	Р	R	S	Т	U	V	W
Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

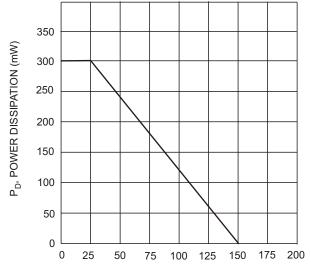




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m V_{DS}}$, DRAIN-SOURCE VOLTAGE (V) Fig. 1 On-Region Characteristics



 T_{j} , JUNCTION TEMPERATURE (°C) Fig. 3 On-Resistance vs Junction Temperature



T_A, AMBIENT TEMPERATURE (°C) Fig. 5, Max Power Dissipation vs Ambient Temperature

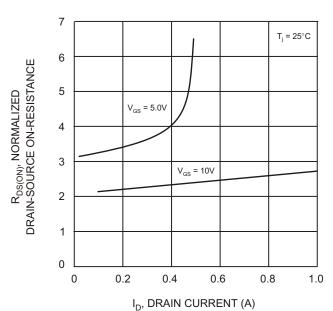
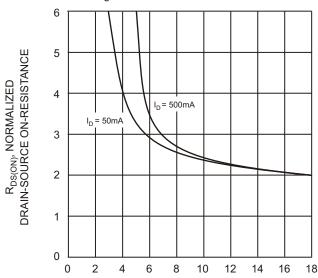


Fig. 2 On-Resistance vs Drain Current



V_{GS}, GATE TO SOURCE VOLTAGE (V) Fig. 4 On-Resistance vs. Gate-Source Voltage



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